NPN Epitaxial Planar Silicon Transistor



2SC4673 UHF Low-Noise Amplifier,

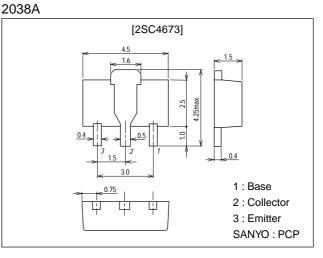
Features

- \cdot Low noise figure : NF=1.5dB typ (f=0.9GHz).
- · High power gain : $|S21e|^2=8.0$ dB typ (f=0.9GHz).
- \cdot High cutoff frequency : f_T=4.5GHz typ.

Package Dimensions

Wide-Band Amplifier Applications

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		20	V
Collector-to-Emitter Voltage	VCEO		12	V
Emitter-to-Base Voltage	VEBO		3	V
Collector Current	IC		100	mA
Base Current	Ι _Β		30	mA
Collector Dissipation	PC		400	mW
		Mounted on ceramic board (250mm ² ×0.8mm)	800	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Falanetei	Symbol	Conditions	min	typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =12V, I _E =0			1.0	μA
Emitter Cutoff Current	IEBO	V _{EB} =2V, I _C =0			10	μA
DC Current Gain	hFE	V _{CE} =10V, I _C =20mA	40*		200*	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =20mA		4.5		GHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		1.1		pF
Reverse Transfer Capacitance	Cre	V _{CB} =10V, f=1MHz		0.75		pF
* : The 2SC3778 is classified by 20mA h_{EE} as for	ollows : 40	C 80 60 D 120 100 E 200				

* : The 2SC3//8 is classified by 20mA h_{FE} as follows : Marking : CD

■ Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.

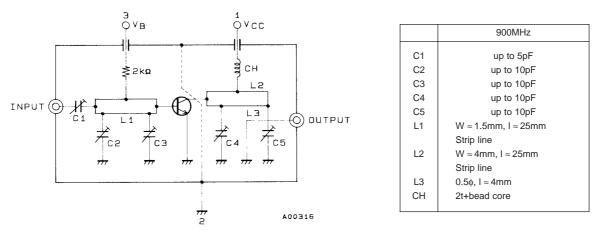
SANYO assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges,or other parameters) listed in products specifications of any and all SANYO products described or contained herein.

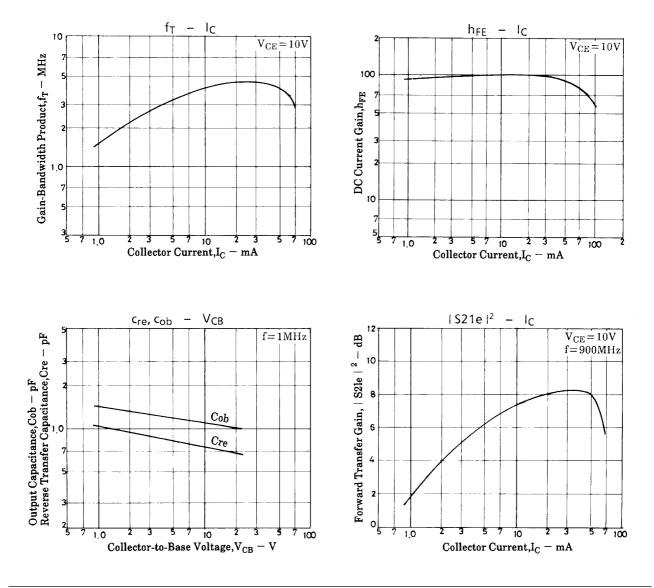
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

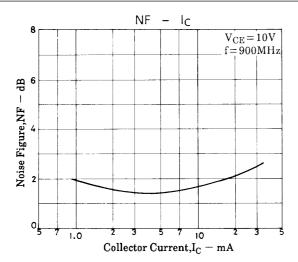
 h_{FE} rank : C, D, E

Parameter	Symbol	Conditions		Ratings		
i didificici	Gymbol			typ	max	Unit
Forward Transfer Gain	S21e ²	V _{CE} =10V, I _C =20mA, f=0.9GHz		8.0		dB
Noise Figure	NF	V _{CE} =10V, I _C =5mA, f=0.9GHz		1.5	3.0	dB

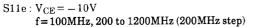
NF Test Circuit

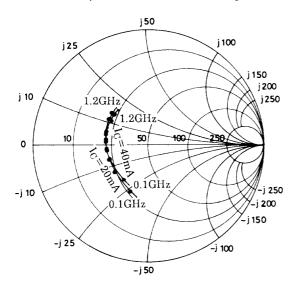




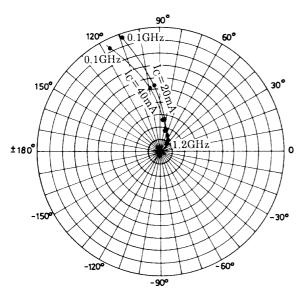


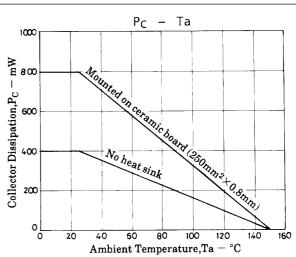
S parameter

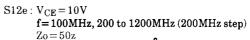


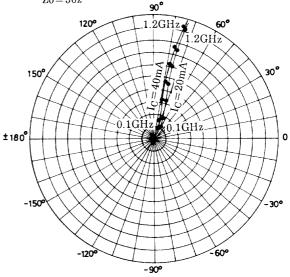


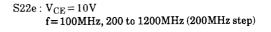
S21e : $V_{CE} = 10V$ f = 100MHz, 200 to 1200MHz (200MHz step)

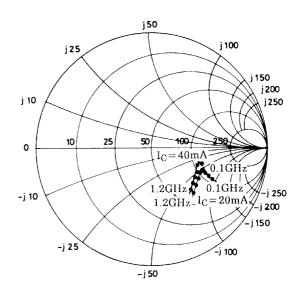












S parameters (Common emitter)

 $V_{CE}=10V, I_{C}=20mA, Z_{O}=50\Omega$

Freq	S ₁₁		s ₂₁		S ₁₂		S ₂₂	
(MHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	0.414	-112.1	18.300	115.9	0.024	61.1	0.605	-26.4
200	0.372	-147.5	10.148	99.2	0.037	66.4	0.492	-23.5
400	0.364	-175.7	5.274	84.8	0.064	72.9	0.458	-23.0
600	0.369	170.1	3.619	75.6	0.093	75.3	0.460	-27.3
800	0.379	158.7	2.764	67.8	0.123	76.6	0.468	-32.6
900	0.366	153.6	2.504	66.4	0.139	75.4	0.475	-35.7
1000	0.388	148.5	2.279	60.8	0.152	75.1	0.478	-38.5
1200	0.399	140.5	1.914	54.2	0.184	74.0	0.487	-44.4

$V_{CE}=10V$, $I_C=40mA$, $Z_O=50\Omega$

Freq (MHz)	S ₁₁		s ₂₁		S ₁₂		S ₂₂	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	0.730	-133.7	19.714	109.3	0.021	66.4	0.535	-25.3
200	0.363	-161.5	10.534	95.3	0.035	72.5	0.452	-20.6
400	0.366	177.6	5.411	82.8	0.064	77.3	0.438	-21.1
600	0.371	166.7	3.690	74.3	0.094	77.9	0.444	-25.9
800	0.380	156.9	2.823	66.8	0.125	77.3	0.454	-31.7
900	0.389	153.1	2.562	63.5	0.142	76.8	0.462	-35.1
1000	0.391	148.3	2.329	59.9	0.155	76.1	0.465	-37.7
1200	0.404	141.3	1.982	53.6	0.186	74.7	0.474	-43.8

- Specifications of any and all SANYO products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Electric Co., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of SANYO Electric Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of January, 1999. Specifications and information herein are subject to change without notice.